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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	M16C/60
Core Size	16-Bit
Speed	24MHz
Connectivity	I ² C, IEBus, UART/USART
Peripherals	DMA, WDT
Number of I/O	50
Program Memory Size	-
Program Memory Type	ROMless
EEPROM Size	-
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30624spfp-u3c

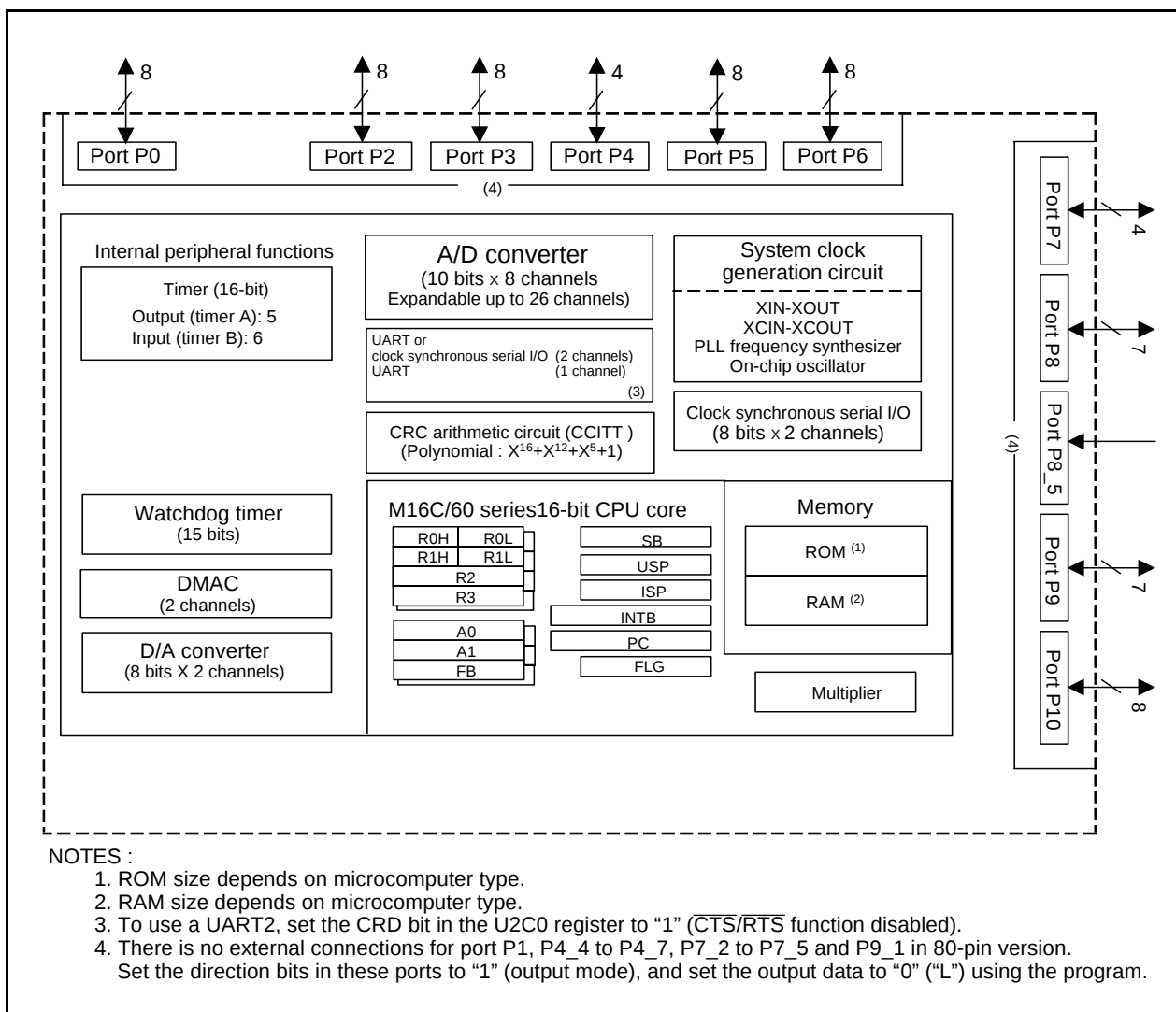


Figure 1.2 M16C/62P Group (M16C/62P, M16C/62PT) 80-pin version Block Diagram

Table 1.6 Product List (3) (T version (M16C/62PT))**As of Dec. 2005**

Type No.	ROM Capacity	RAM Capacity	Package Type ⁽¹⁾	Remarks	
M3062CM6T-XXXFP (D)	48 Kbytes	4 Kbytes	PRQP0100JB-A	Mask ROM version	T Version (High reliability 85°C version)
M3062CM6T-XXXGP (D)			PLQP0100KB-A		
M3062EM6T-XXXGP (P)			PRQP0080JA-A		
M3062CM8T-XXXFP (D)	64 Kbytes	4 Kbytes	PRQP0100JB-A		
M3062CM8T-XXXGP (D)			PLQP0100KB-A		
M3062EM8T-XXXGP (P)			PRQP0080JA-A		
M3062CMAT-XXXFP (D)	96 Kbytes	5 Kbytes	PRQP0100JB-A		
M3062CMAT-XXXGP (D)			PLQP0100KB-A		
M3062EMAT-XXXGP (P)			PRQP0080JA-A		
M3062AMCT-XXXFP (D)	128 Kbytes	10 Kbytes	PRQP0100JB-A		
M3062AMCT-XXXGP (D)			PLQP0100KB-A		
M3062BMCT-XXXGP (P)			PRQP0080JA-A		
M3062CF8TFP (D)	64 K+4 Kbytes	4 Kbytes	PRQP0100JB-A	Flash memory version ⁽²⁾	
M3062CF8TGP			PLQP0100KB-A		
M3062AFCTFP (D)	128K+4 Kbytes	10 Kbytes	PRQP0100JB-A		
M3062AFCTGP (D)			PLQP0100KB-A		
M3062BFCTGP (P)			PRQP0080JA-A		
M3062JFHTFP (D)	384K+4 Kbytes	31 Kbytes	PRQP0100JB-A		
M3062JFHTGP (D)			PLQP0100KB-A		

(D): Under development

(P): Under planning

NOTES:

- The old package type numbers of each package type are as follows.
PRQP0100JB-A : 100P6S-A,
PLQP0100KB-A : 100P6Q-A,
PRQP0080JA-A : 80P6S-A
- In the flash memory version, there is 4K bytes area (block A).

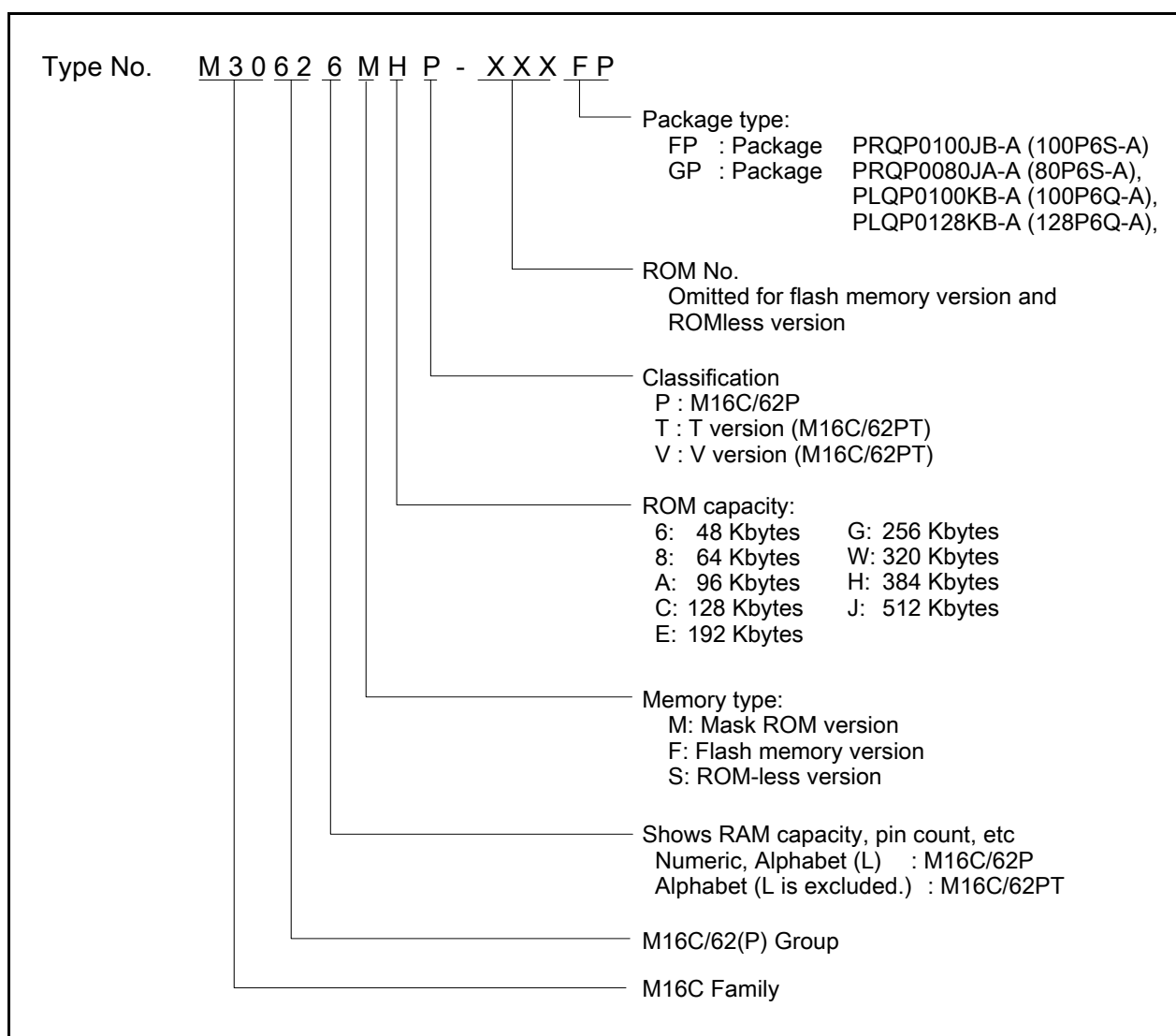
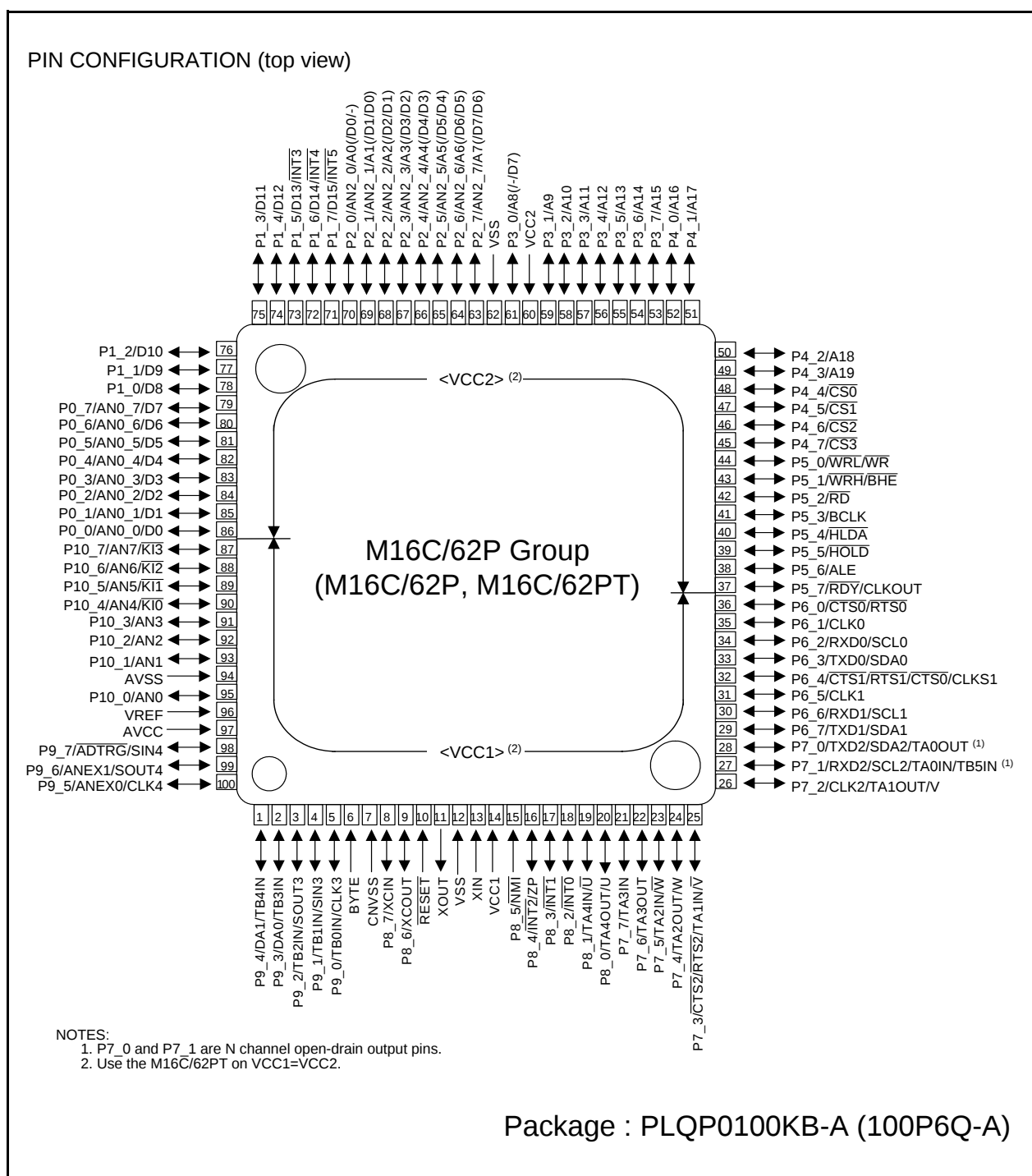


Figure 1.3 Type No., Memory Size, and Package



2.8.8 Stack Pointer Select Flag (U Flag)

ISP is selected when the U flag is “0”; USP is selected when the U flag is “1”.

The U flag is cleared to “0” when a hardware interrupt request is accepted or an INT instruction for software interrupt Nos. 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is configured with three bits, for specification of up to eight processor interrupt priority levels from level 0 to level 7.

If a requested interrupt has priority greater than IPL, the interrupt is enabled.

2.8.10 Reserved Area

When write to this bit, write “0”. When read, its content is indeterminate.

Table 4.3 SFR Information (3) ⁽¹⁾

Address	Register	Symbol	After Reset
0080h			
0081h			
0082h			
0083h			
0084h			
0085h			
0086h			
0087h to 01AFh			
01B0h			
01B1h			
01B2h			
01B3h			
01B4h	Flash Identification Register ⁽²⁾	FIDR	XXXXXX00b
01B5h	Flash Memory Control Register 1 ⁽²⁾	FMR1	0X00XX0Xb
01B6h			
01B7h	Flash Memory Control Register 0 ⁽²⁾	FMR0	00000001b
01B8h	Address Match Interrupt Register 2	RMAD2	00h
01B9h			00h
01BAh			XXh
01BBh			XXXXXX00b
01BCh	Address Match Interrupt Register 3	RMAD3	00h
01BDh			00h
01BEh			XXh
01C0h to 024Fh			
0250h			
0251h			
0252h			
0253h			
0254h			
0255h			
0256h			
0257h			
0258h			
0259h			
025Ah			
025Bh			
025Ch			
025Dh			
025Eh	Peripheral Clock Select Register	PCLKR	00000011b
025Fh			
0260h to 032Fh			
0330h			
0331h			
0332h			
0333h			
0334h			
0335h			
0336h			
0337h			
0338h			
0339h			
033Ah			
033Bh			
033Ch			
033Dh			
033Eh			
033Fh			

NOTES:

1. The blank areas are reserved and cannot be accessed by users.
2. This register is included in the flash memory version.

X : Nothing is mapped to this bit

Table 4.5 SFR Information (5) ⁽¹⁾

Address	Register	Symbol	After Reset
0380h	Count Start Flag	TABSR	00h
0381h	Clock Prescaler Reset Flag	CPSRF	0XXXXXXb
0382h	One-Shot Start Flag	ONSF	00h
0383h	Trigger Select Register	TRGSR	00h
0384h	Up-Down Flag	UDF	00h ⁽²⁾
0385h			
0386h	Timer A0 Register	TA0	XXh
0387h			XXh
0388h	Timer A1 Register	TA1	XXh
0389h			XXh
038Ah	Timer A2 Register	TA2	XXh
038Bh			XXh
038Ch	Timer A3 Register	TA3	XXh
038Dh			XXh
038Eh	Timer A4 Register	TA4	XXh
038Fh			XXh
0390h	Timer B0 Register	TB0	XXh
0391h			XXh
0392h	Timer B1 Register	TB1	XXh
0393h			XXh
0394h	Timer B2 Register	TB2	XXh
0395h			XXh
0396h	Timer A0 Mode Register	TA0MR	00h
0397h	Timer A1 Mode Register	TA1MR	00h
0398h	Timer A2 Mode Register	TA2MR	00h
0399h	Timer A3 Mode Register	TA3MR	00h
039Ah	Timer A4 Mode Register	TA4MR	00h
039Bh	Timer B0 Mode Register	TB0MR	00XX0000b
039Ch	Timer B1 Mode Register	TB1MR	00XX0000b
039Dh	Timer B2 Mode Register	TB2MR	00XX0000b
039Eh	Timer B2 Special Mode Register	TB2SC	XXXXXX00b
039Fh			
03A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
03A1h	UART0 Bit Rate Generator	U0BRG	XXh
03A2h	UART0 Transmit Buffer Register	U0TB	XXh
03A3h			XXh
03A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
03A5h	UART0 Transmit/Receive Control Register 1	U0C1	00XX0010b
03A6h	UART0 Receive Buffer Register	U0RB	XXh
03A7h			XXh
03A8h	UART1 Transmit/Receive Mode Register	U1MR	00h
03A9h	UART1 Bit Rate Generator	U1BRG	XXh
03AAh	UART1 Transmit Buffer Register	U1TB	XXh
03ABh			XXh
03ACh	UART1 Transmit/Receive Control Register 0	U1C0	00001000b
03ADh	UART1 Transmit/Receive Control Register 1	U1C1	00XX0010b
03AEh	UART1 Receive Buffer Register	U1RB	XXh
03AFh			XXh
03B0h	UART Transmit/Receive Control Register 2	UCON	X0000000b
03B1h			
03B2h			
03B3h			
03B4h			
03B5h			
03B6h			
03B7h			
03B8h	DMA0 Request Factor Select Register	DM0SL	00h
03B9h			
03BAh	DMA1 Request Factor Select Register	DM1SL	00h
03BBh			
03BCh	CRC Data Register	CRCD	XXh
03BDh			XXh
03BEh	CRC Input Register	CRCIN	XXh
03BFh			

NOTES:

1. The blank areas are reserved and cannot be accessed by users.
2. Bit 5 in the Up-down flag is "0" by reset. However, The values in these bits when read are indeterminate.

X : Nothing is mapped to this bit

Table 5.4 A/D Conversion Characteristics (1)

Symbol	Parameter		Measuring Condition		Standard			Unit
					Min.	Typ.	Max.	
–	Resolution		VREF=VCC1				10	Bits
INL	Integral Non-Linearity Error	10bit	VREF=VCC1=5V	AN0 to AN7 input, AN0_0 to AN0_7 input, AN2_0 to AN2_7 input, ANEX0, ANEX1 input			±3	LSB
				External operation amp connection mode			±7	LSB
			VREF=VCC1=3.3V	AN0 to AN7 input, AN0_0 to AN0_7 input, AN2_0 to AN2_7 input, ANEX0, ANEX1 input			±5	LSB
				External operation amp connection mode			±7	LSB
		8bit	VREF=VCC1=5V, 3.3V				±2	LSB
		–	Absolute Accuracy	10bit	VREF=VCC1=5V	AN0 to AN7 input, AN0_0 to AN0_7 input, AN2_0 to AN2_7 input, ANEX0, ANEX1 input		
External operation amp connection mode						±7	LSB	
VREF=VCC1=3.3V	AN0 to AN7 input, AN0_0 to AN0_7 input, AN2_0 to AN2_7 input, ANEX0, ANEX1 input					±5	LSB	
	External operation amp connection mode					±7	LSB	
8bit	VREF=VCC1=5V, 3.3V					±2	LSB	
–	Tolerance Level Impedance						3	
DNL	Differential Non-Linearity Error						±1	LSB
–	Offset Error						±3	LSB
–	Gain Error						±3	LSB
RLADDER	Ladder Resistance		VREF=VCC1		10		40	kΩ
tCONV	10-bit Conversion Time, Sample & Hold Available		VREF=VCC1=5V, φAD=12MHz		2.75			μs
tCONV	8-bit Conversion Time, Sample & Hold Available		VREF=VCC1=5V, φAD=12MHz		2.33			μs
tsAMP	Sampling Time				0.25			μs
VREF	Reference Voltage				2.0		VCC1	V
VIA	Analog Input Voltage				0		VREF	V

NOTES:

1. Referenced to VCC1=AVCC=VREF=3.3 to 5.5V, VSS=AVSS=0V at T_{opr} = –20 to 85°C / –40 to 85°C unless otherwise specified.
2. If VCC1 > VCC2, do not use AN0_0 to AN0_7 and AN2_0 to AN2_7 as analog input pins.
3. φAD frequency must be 12 MHz or less. And divide the fAD if VCC1 is less than 4.0V, and φAD frequency into 10 MHz or less.
4. When sample & hold is disabled, φAD frequency must be 250 kHz or more, in addition to the limitation in Note 3.
When sample & hold is enabled, φAD frequency must be 1MHz or more, in addition to the limitation in Note 3.

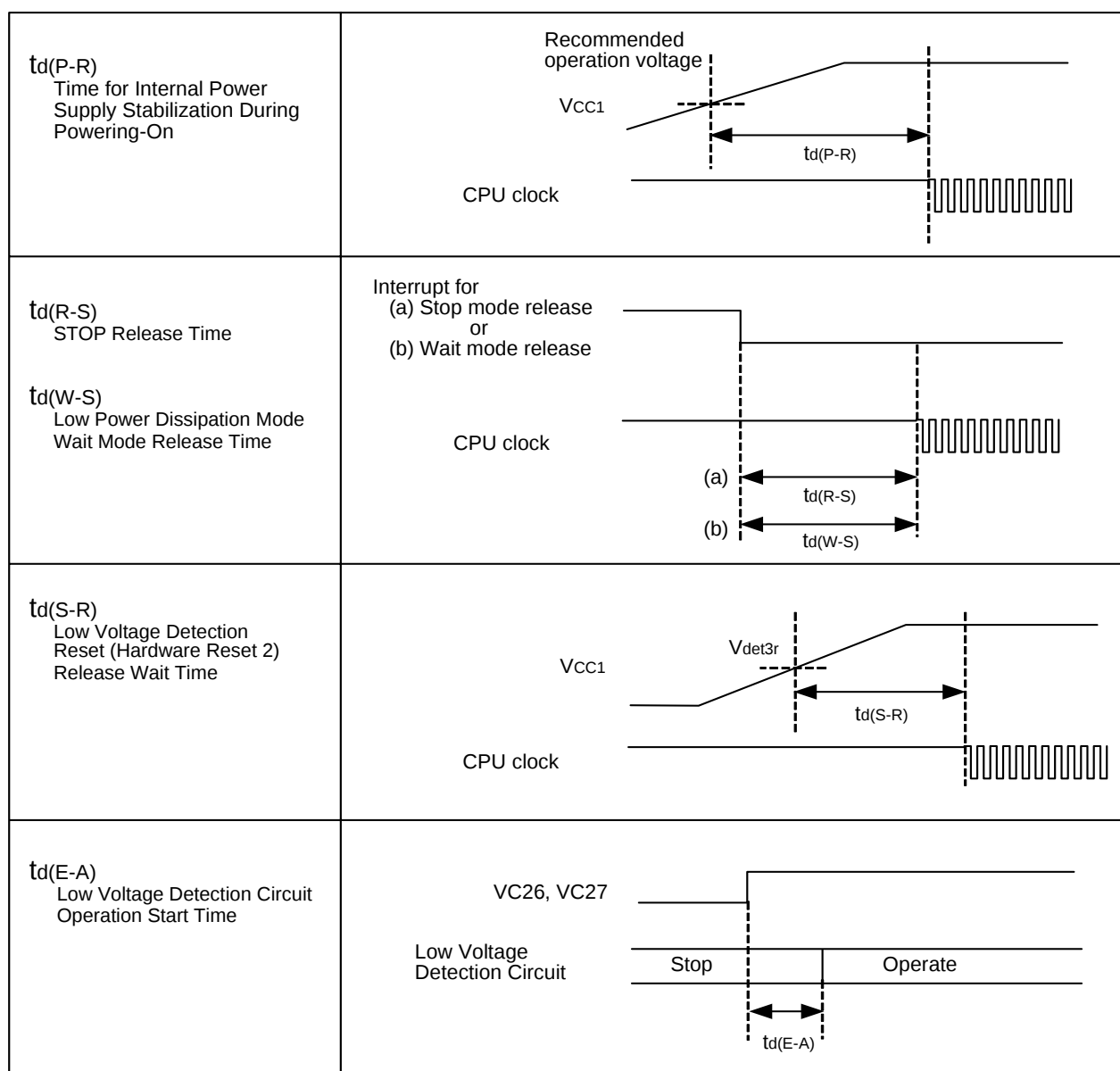


Figure 5.1 Power Supply Circuit Timing Diagram

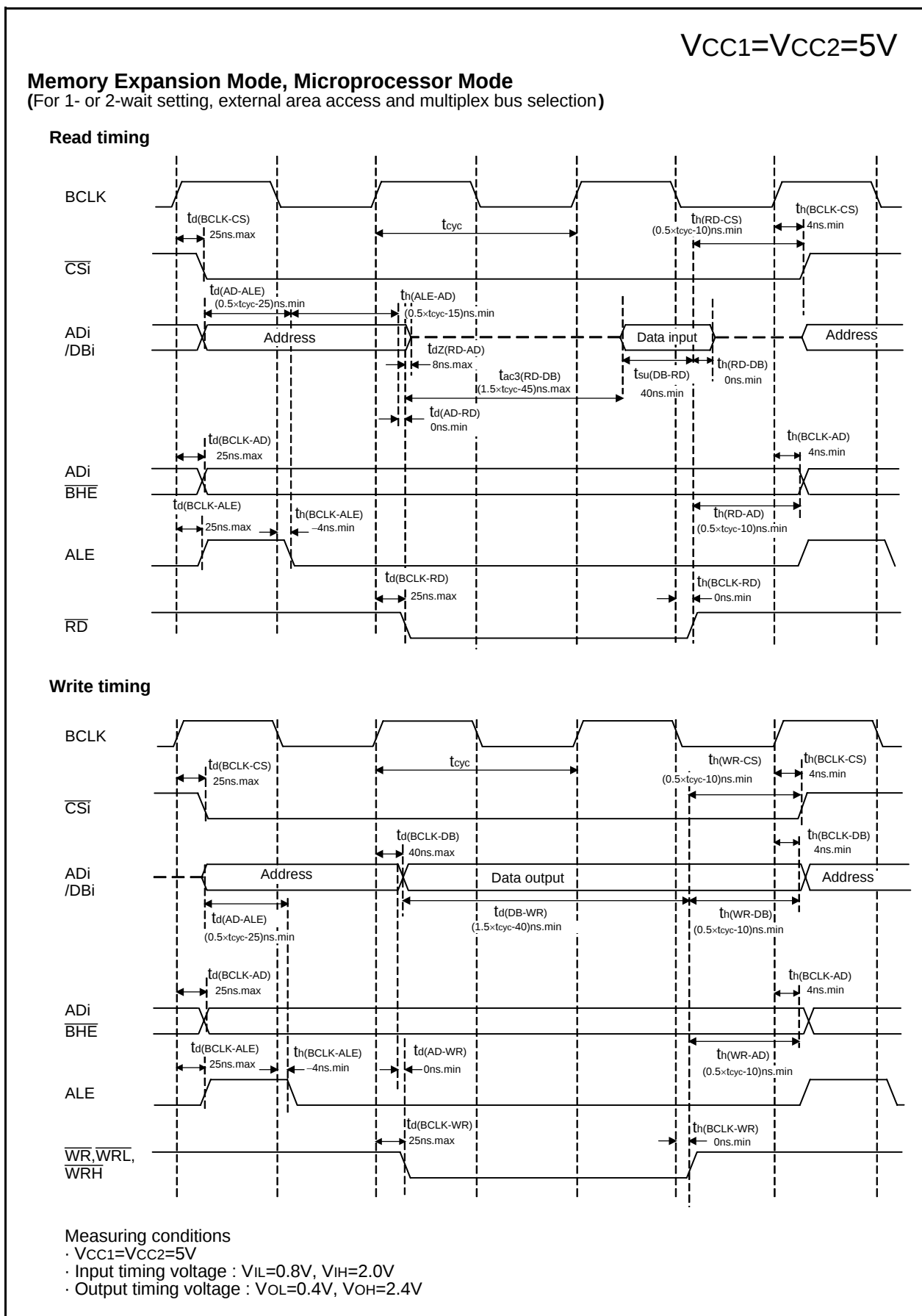


Figure 5.10 Timing Diagram (8)

Table 5.31 Electrical Characteristics (2) ⁽¹⁾

Symbol	Parameter		Measuring Condition		Standard			Unit
					Min.	Typ.	Max.	
I _{cc}	Power Supply Current (V _{cc1} =V _{cc2} =2.7V to 3.6V)	In single-chip mode, the output pins are open and other pins are V _{ss}	Mask ROM	f(BCLK)=10MHz No division		8	11	mA
				No division, On-chip oscillation		1		mA
			Flash Memory	f(BCLK)=10MHz, No division		8	13	mA
				No division, On-chip oscillation		1.8		mA
			Flash Memory Program	f(BCLK)=10MHz, VCC1=3.0V		12		mA
			Flash Memory Erase	f(BCLK)=10MHz, VCC1=3.0V		22		mA
			Mask ROM	f(XCIN)=32kHz Low power dissipation mode, ROM ⁽³⁾		25		μA
			Flash Memory	f(BCLK)=32kHz Low power dissipation mode, RAM ⁽³⁾		25		μA
				f(BCLK)=32kHz Low power dissipation mode, Flash Memory ⁽³⁾		420		μA
				On-chip oscillation, Wait mode		45		μA
				Mask ROM Flash Memory	f(BCLK)=32kHz Wait mode ⁽²⁾ , Oscillation capability High		6.0	
			f(BCLK)=32kHz Wait mode ⁽²⁾ , Oscillation capability Low			1.8		μA
			Stop mode T _{opr} =25°C			0.7	3.0	μA
I _{det4}	Low Voltage Detection Dissipation Current ⁽⁴⁾					0.6	4	μA
I _{det3}	Reset Area Detection Dissipation Current ⁽⁴⁾					0.4	2	μA

NOTES:

1. Referenced to V_{CC1}=V_{CC2}=2.7 to 3.3V, V_{SS} = 0V at T_{opr} = -20 to 85°C / -40 to 85°C, f(BCLK)=10MHz unless otherwise specified.
2. With one timer operated using fC32.
3. This indicates the memory in which the program to be executed exists.
4. I_{det} is dissipation current when the following bit is set to "1" (detection circuit enabled).
I_{det4}: VC27 bit in the VCR2 register
I_{det3}: VC26 bit in the VCR2 register

$$V_{CC1}=V_{CC2}=3V$$

Timing Requirements

($V_{CC1} = V_{CC2} = 3V$, $V_{SS} = 0V$, at $T_{opr} = -20$ to $85^{\circ}C$ / -40 to $85^{\circ}C$ unless otherwise specified)

Table 5.34 Timer A Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	150		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	60		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	60		ns

Table 5.35 Timer A Input (Gating Input in Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	600		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	300		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	300		ns

Table 5.36 Timer A Input (External Trigger Input in One-shot Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	300		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	150		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	150		ns

Table 5.37 Timer A Input (External Trigger Input in Pulse Width Modulation Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	150		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	150		ns

Table 5.38 Timer A Input (Counter Increment/Decrement Input in Event Counter Mode)

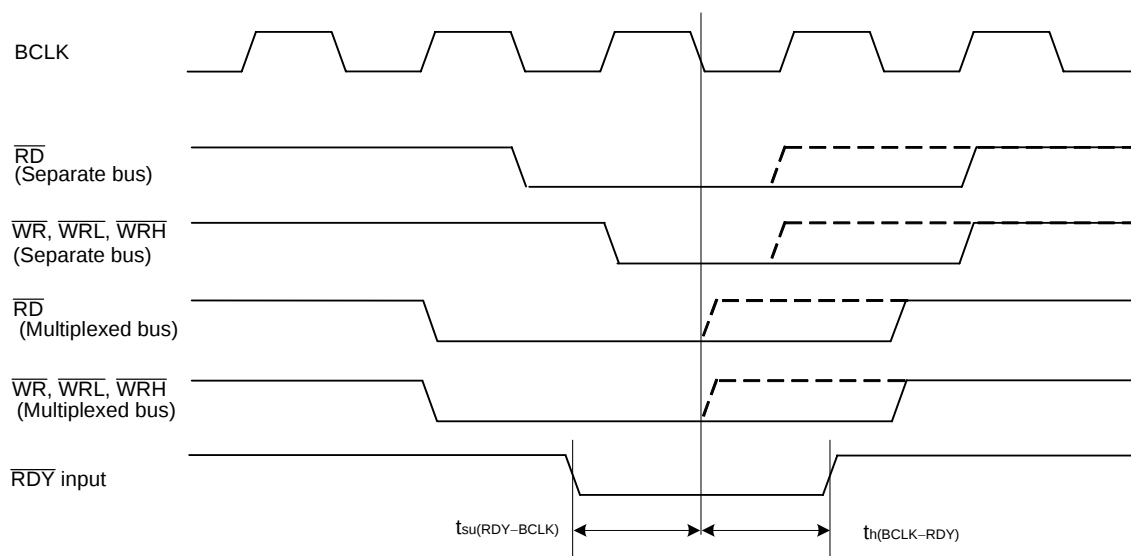
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(UP)}$	TAiOUT Input Cycle Time	3000		ns
$t_{w(UPH)}$	TAiOUT Input HIGH Pulse Width	1500		ns
$t_{w(UPL)}$	TAiOUT Input LOW Pulse Width	1500		ns
$t_{su(UP-TIN)}$	TAiOUT Input Setup Time	600		ns
$t_{h(TIN-UP)}$	TAiOUT Input Hold Time	600		ns

Table 5.39 Timer A Input (Two-phase Pulse Input in Event Counter Mode)

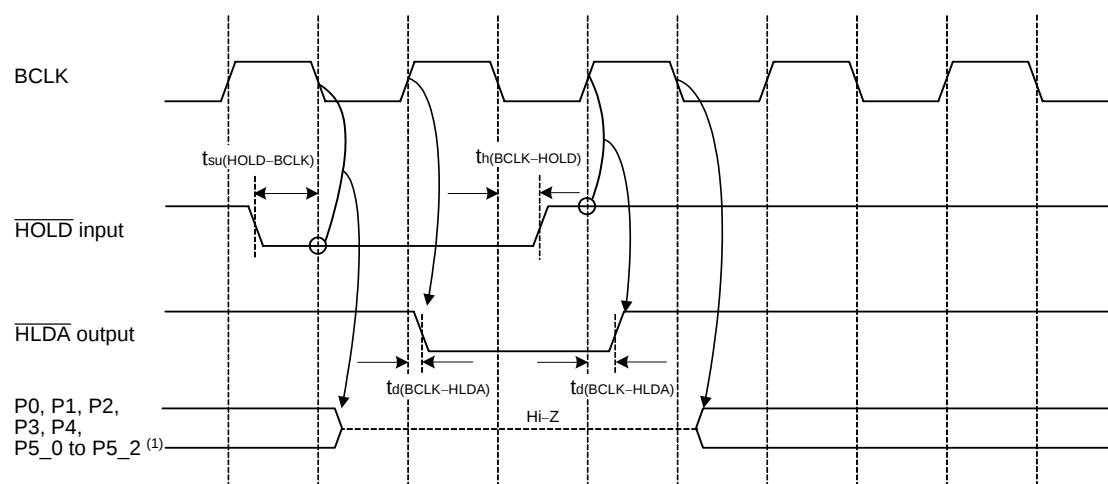
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	2		μs
$t_{su(TAIN-TAOUT)}$	TAiOUT Input Setup Time	500		ns
$t_{su(TAOUT-TAIN)}$	TAiIN Input Setup Time	500		ns

Memory Expansion Mode, Microprocessor Mode

(Effective for setting with wait)

 $V_{CC1}=V_{CC2}=3V$ 

(Common to setting with wait and setting without wait)

**NOTES:**

1. These pins are set to high-impedance regardless of the input level of the BYTE pin, PM06 bit in PM0 register and PM11 bit in PM1 register.

Measuring conditions :

- $V_{CC1}=V_{CC2}=3V$
- Input timing voltage : Determined with $V_{IL}=0.6V$, $V_{IH}=2.4V$
- Output timing voltage : Determined with $V_{OL}=1.5V$, $V_{OH}=1.5V$

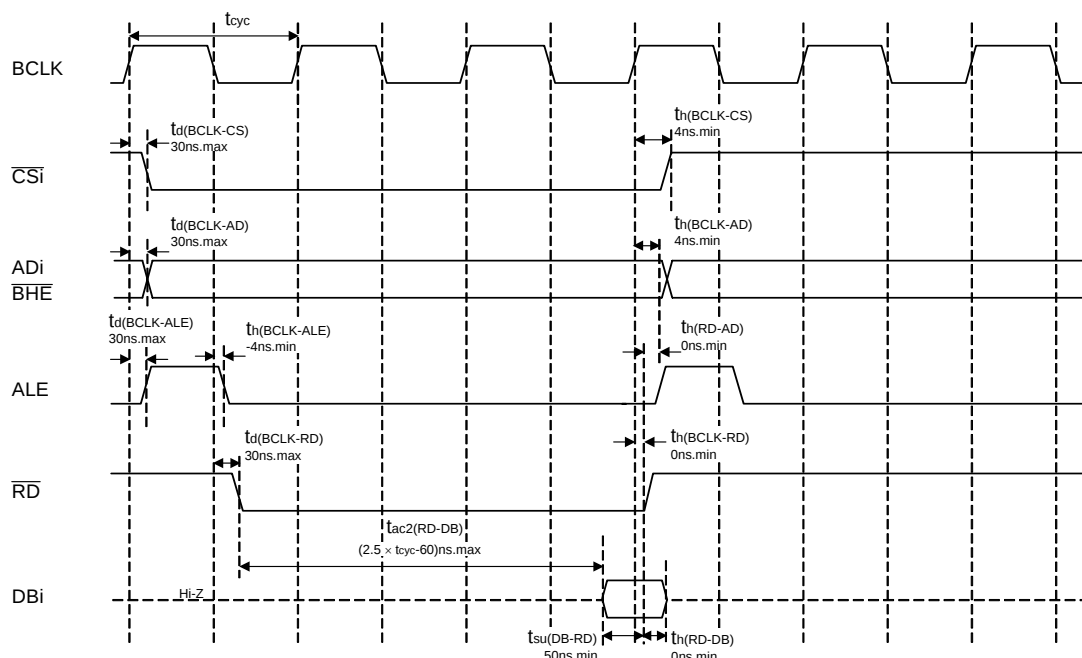
Figure 5.15 Timing Diagram (3)

Memory Expansion Mode, Microprocessor Mode

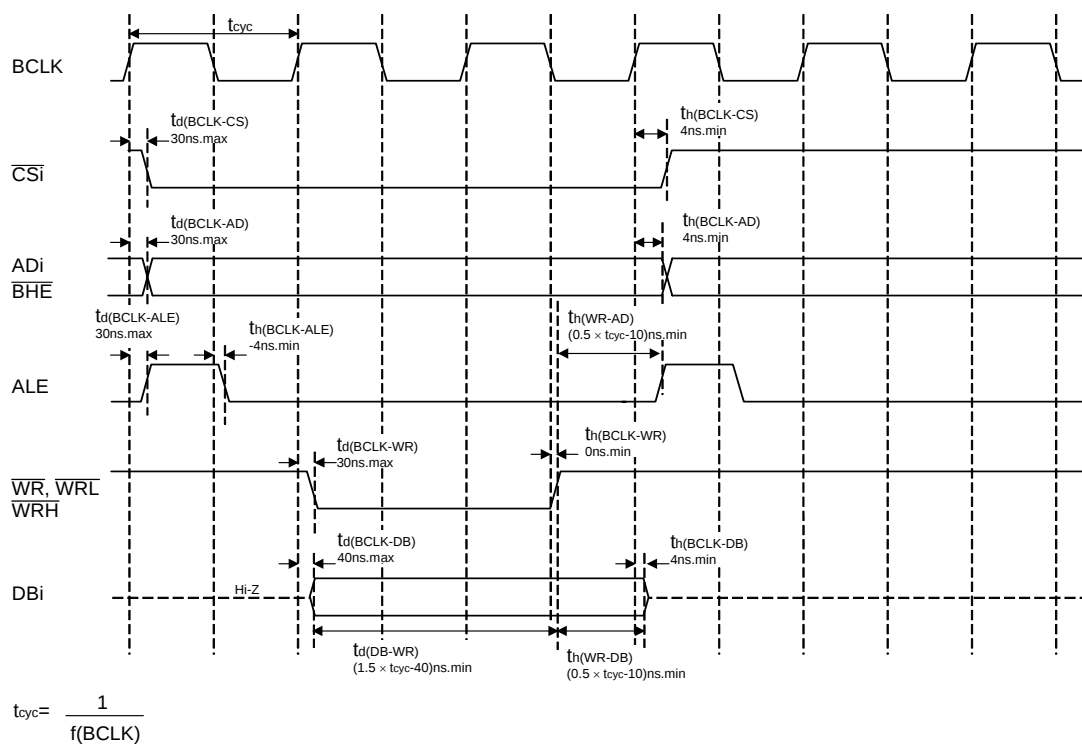
(for 2-wait setting and external area access)

 $V_{CC1}=V_{CC2}=3V$

Read timing



Write timing



Measuring conditions

- $V_{CC1}=V_{CC2}=3V$
- Input timing voltage : $V_{IL}=0.6V$, $V_{IH}=2.4V$
- Output timing voltage : $V_{OL}=1.5V$, $V_{OH}=1.5V$

Figure 5.18 Timing Diagram (6)

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1} = V_{CC2} = 5V$, $V_{SS} = 0V$, at $T_{opr} = -40$ to $85^{\circ}C$ (T version) / -40 to $125^{\circ}C$ (V version) unless otherwise specified)

Table 5.59 External Clock Input (XIN input)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External Clock Input Cycle Time	62.5		ns
$t_{w(H)}$	External Clock Input HIGH Pulse Width	25		ns
$t_{w(L)}$	External Clock Input LOW Pulse Width	25		ns
t_r	External Clock Rise Time		15	ns
t_f	External Clock Fall Time		15	ns

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1} = V_{CC2} = 5V$, $V_{SS} = 0V$, at $T_{opr} = -40$ to $85^{\circ}C$ (T version) / -40 to $125^{\circ}C$ (V version) unless otherwise specified)

Table 5.66 Timer B Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN Input Cycle Time (counted on one edge)	100		ns
$t_{w(TBH)}$	TBiIN Input HIGH Pulse Width (counted on one edge)	40		ns
$t_{w(TBL)}$	TBiIN Input LOW Pulse Width (counted on one edge)	40		ns
$t_{c(TB)}$	TBiIN Input Cycle Time (counted on both edges)	200		ns
$t_{w(TBH)}$	TBiIN Input HIGH Pulse Width (counted on both edges)	80		ns
$t_{w(TBL)}$	TBiIN Input LOW Pulse Width (counted on both edges)	80		ns

Table 5.67 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN Input Cycle Time	400		ns
$t_{w(TBH)}$	TBiIN Input HIGH Pulse Width	200		ns
$t_{w(TBL)}$	TBiIN Input LOW Pulse Width	200		ns

Table 5.68 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN Input Cycle Time	400		ns
$t_{w(TBH)}$	TBiIN Input HIGH Pulse Width	200		ns
$t_{w(TBL)}$	TBiIN Input LOW Pulse Width	200		ns

Table 5.69 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(AD)}$	$\overline{ADTRG}$ Input Cycle Time	1000		ns
$t_{w(ADL)}$	$\overline{ADTRG}$ input LOW Pulse Width	125		ns

Table 5.70 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi Input Cycle Time	200		ns
$t_{w(CKH)}$	CLKi Input HIGH Pulse Width	100		ns
$t_{w(CKL)}$	CLKi Input LOW Pulse Width	100		ns
$t_{d(C-Q)}$	TXDi Output Delay Time		80	ns
$t_{h(C-Q)}$	TXDi Hold Time	0		ns
$t_{su(D-C)}$	RXDi Input Setup Time	70		ns
$t_{h(C-D)}$	RXDi Input Hold Time	90		ns

Table 5.71 External Interrupt $\overline{INTi}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INTi}$ Input HIGH Pulse Width	250		ns
$t_{w(INL)}$	$\overline{INTi}$ Input LOW Pulse Width	250		ns

$$V_{CC1}=V_{CC2}=5V$$

Switching Characteristics

($V_{CC1} = V_{CC2} = 5V$, $V_{SS} = 0V$, at $T_{opr} = -40$ to $85^{\circ}C$ (T version) / -40 to $125^{\circ}C$ (V version) unless otherwise specified)

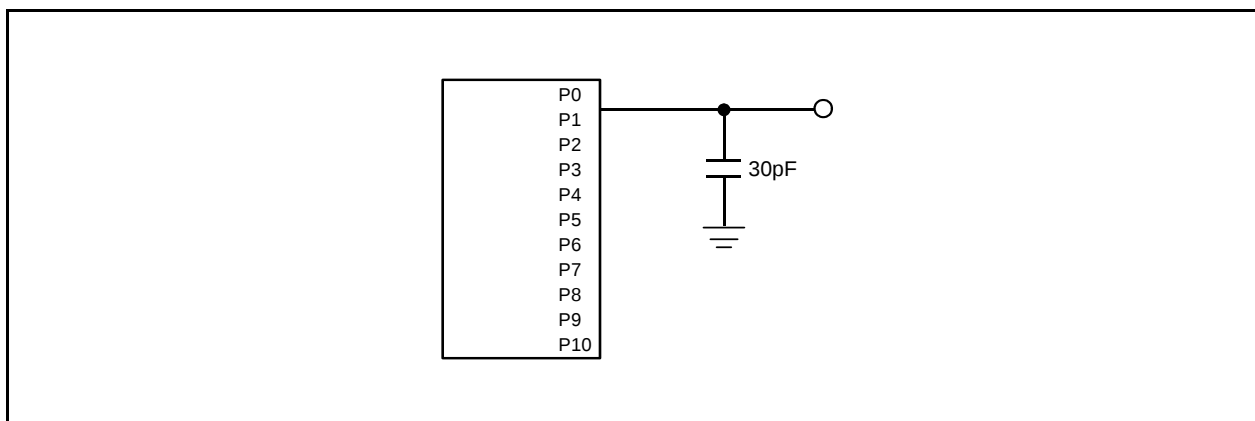


Figure 5.23 Ports P0 to P10 Measurement Circuit

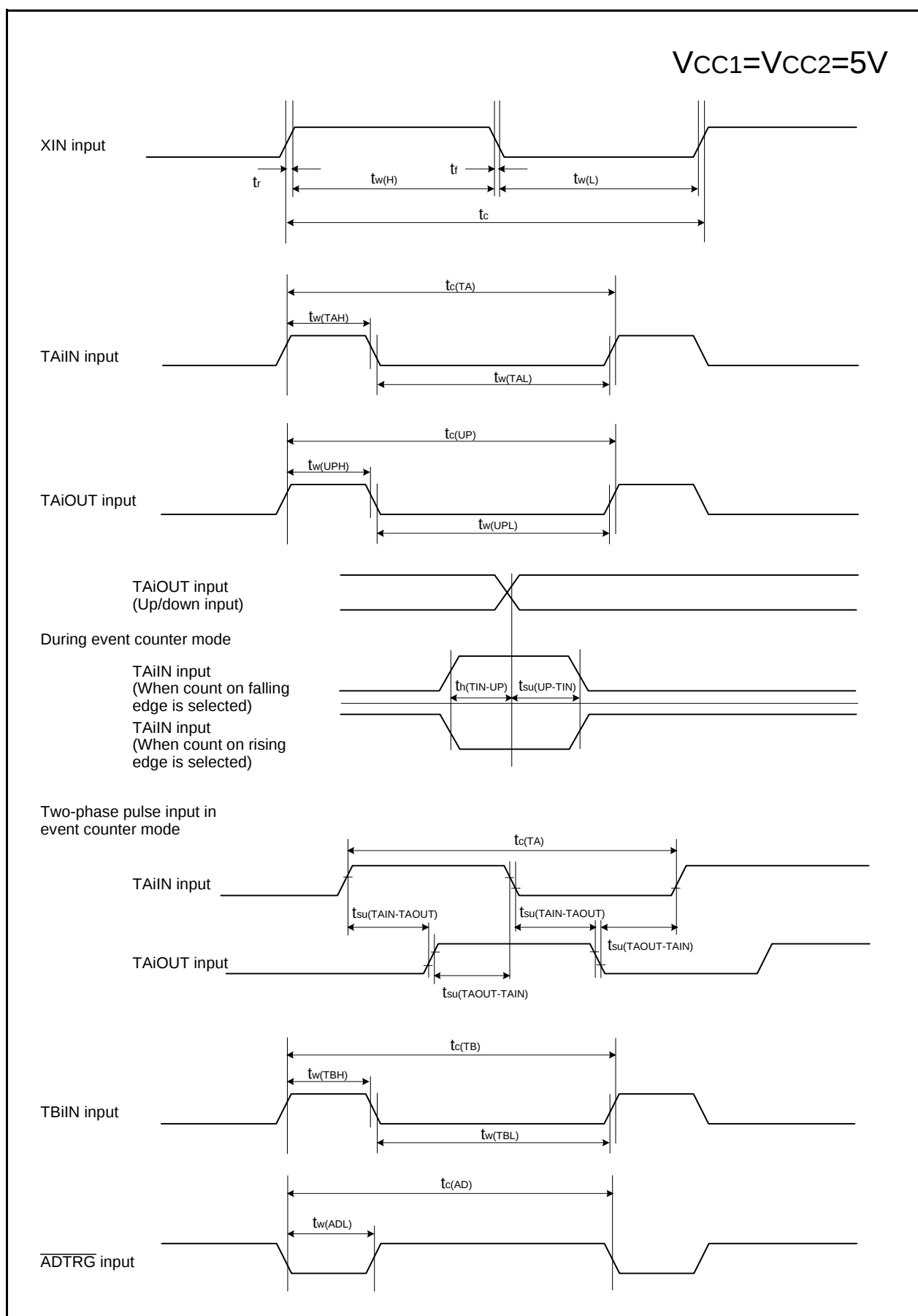


Figure 5.24 Timing Diagram (1)

REVISION HISTORY		M16C/62P Group (M16C/62P, M16C/62PT) Hardware Manual	
Rev.	Date	Description	
		Page	Summary
		40	Table 5.24 is partly revised.
		57	Table 5.43 is partly revised.
		70	Table 5.48 is partly revised.
		72	Table 5.50 is partly revised.
		73	Table 5.53 is partly revised.
		74	Table 5.55 is revised.
		76	Table 5.57 is partly revised.
		79	Table 5.69 is partly revised.
2.41	Jan 01, 2006	-	voltage down detection reset -> brown-out detection Reset
		2-4	Tables 1.1 to 1.3 Performance outline of M16C/62P group are partly revised.
		7	Table 1.4 Product List (1) is partly revised. Note 1 is added.
		8	Table 1.5 Product List (2) is partly revised. Note 1, 2 and 3 are added.
		9	Table 1.6 Product List (3) is partly revised. Note 1 and 2 are added.
		10	Table 1.7 Product List (4) is partly revised. Note 1 and 2 are added.
		11	Figure 1.3 Type No., Memory Size, Shows RAM capacity, and Package is partly revised
		12	Table 1.8 Product Code of Flash Memory version and ROMless version for M16C/62P is partly revised.
		13	Table 1.9 Product Code of Flash Memory version for M16C/62P is partly revised.
		14	Figure 1.6 Pin Configuration (Top View) is partly revised.
		15-17	Tables 1.10 to 1.12 Pin Characteristics for 128-Pin Package are added.
		18-19	Figure 1.7 and 1.8 Pin Configuration (Top View) are partly revised.
		20-21	Tables 1.13 to 1.14 Pin Characteristics for 100-Pin Package are added.
		22	Figure 1.9 Pin Configuration (Top View) is partly revised.
		23-24	Tables 1.15 to 1.16 Pin Characteristics for 80-Pin Package are added.
		25-29	Tables 1.17 to 1.21 are partly revised.
		34	Note 4 of Table 4.1 SFR Information is partly revised.
		43	Table 5.4 A/D Conversion Characteristics is partly revised.
		45	Table 5.6 Flash Memory Version Electrical Characteristics for 100 cycle products is partly revised. Table 5.7 Flash Memory Version Electrical Characteristics for 10,000 cycle products is partly revised. Table 5.8 Flash Memory Version Program / Erase Voltage and Read Operation Voltage Characteristics is partly revised.
		46	Table 5.9 Low Voltage Detection Circuit Electrical Characteristics is partly revised.

REVISION HISTORY		M16C/62P Group (M16C/62P, M16C/62PT) Hardware Manual	
Rev.	Date	Description	
		Page	Summary
		47	Figure 5.1 Power Supply Circuit Timing Diagram is partly revised.
		48	Table 5.11 Electrical Characteristics (1) is partly deleted.
		49	Table 5.12 Electrical Characteristics (2) is partly revised.
		50	Note 1 of Table 5.13 External Clock Input (XIN input) is added.
		67	Notes 1 to 4 of Table 5.32 External Clock Input (XIN input) are added.
		85	Table 5.53 Flash Memory Version Electrical Characteristics for 100 cycle products is partly revised. Standard (Min.) is partly revised. Table 5.54 Flash Memory Version Electrical Characteristics for 10,000 cycle products is partly revised. Standard (Min.) is partly revised. Note 5 is revised. Table 23.55 Flash Memory Version Program / Erase Voltage and Read Operation Voltage Characteristics is partly revised.
		87	Table 5.57 Electrical Characteristics (1) is partly deleted.
		88	Table 5.58 Electrical Characteristics is partly revised.